

30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-6.4A

Features

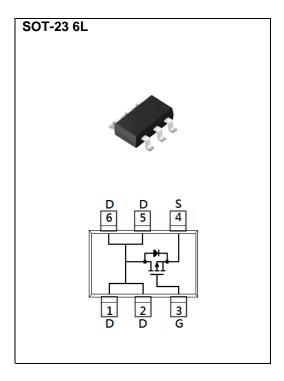
- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-4A<32m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_{D}@-2A<46m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.0142 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V _{DS}	-30	V		
Gate-Source Voltage		V _{GS}			<u>+</u> 20
Continuous Drain Current(Note 4)		I _D	-6.4	А	
Pulsed Drain Current ^(Note 1)		I _{DM}	-25.6		
Power Dissipation	T _a =25°C	_	2	W	
	Derate above 25°C	l P _D	16	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 4,5)		R _{θJA}	62.5	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.6	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4A	-	27	32	32 46 mΩ	
		V _{GS} =-4.5V, I _D =-2A	-	38	46		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Q_g		-	7.8	-	nC	
Gate-Source Charge	Q_gs	V _{DS} =-15V, I _D =-5A,	-	2.7	-		
Gate-Drain Charge	Q_gd	VGS=-4.5 V (1000 2,0)	-	2.8	-		
Input Capacitance	Ciss	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	870	-	pF	
Output Capacitance	Coss	V _{DS} =-15V, V _{GS} =0V, f=1MHZ	-	130	-		
Reverse Transfer Capacitance	Crss	I=IIVIMZ	-	93	-		
Turn-On Delay Time	td _(on)		-	6.5	-		
Turn-On Rise Time	tr	V _{DD} =-15V, I _D =-1A,	-	8.8	-		
Turn-Off Delay Time	td _(off)	$V_{GS}=-10V$, $R_{G}=6\Omega^{(Note 2,3)}$	-	73	-	ns	
Turn-Off Fall Time	tf	KG=077(1919 7'19)	-	44	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is			-	-2	Α	
Diode Forward Current	IS		_	_	-2	A	
Diode Forward Voltage	V_{SD}	I _S =-1A, V _G S=0V	-	-0.75	-1	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing



TYPICAL CHARACTERISTIC CURVES

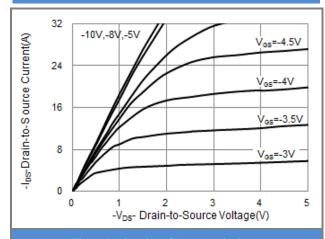


Fig.1 On-Region Characteristics

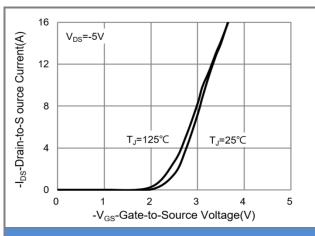


Fig.2 Transfer Characteristics

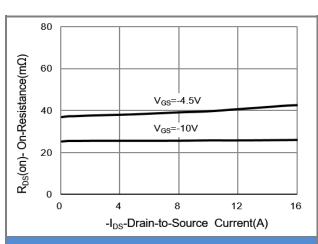


Fig.3 On-Resistance vs. Drain Current

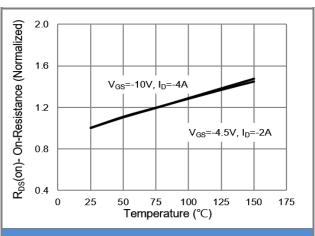
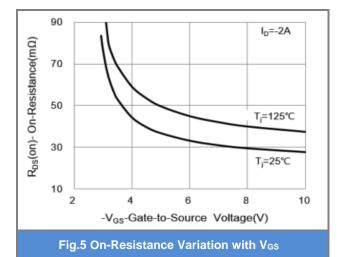


Fig.4 On-Resistance vs. Junction temperature



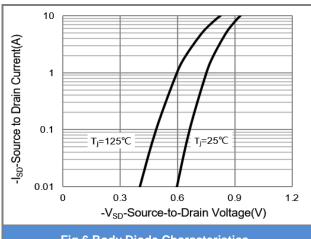


Fig.6 Body Diode Characteristics



TYPICAL CHARACTERISTIC CURVES

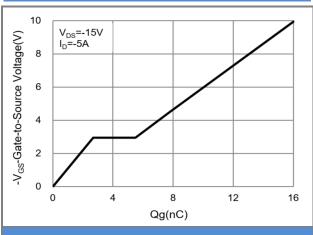


Fig.7 Gate-Charge Characteristics

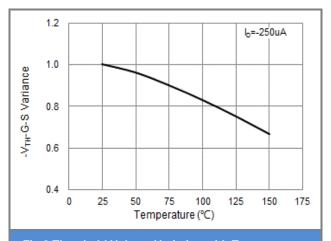


Fig.8 Threshold Voltage Variation with Temperature

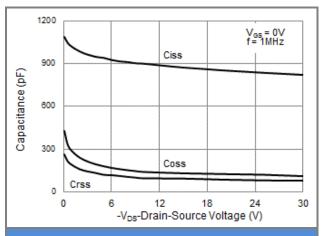


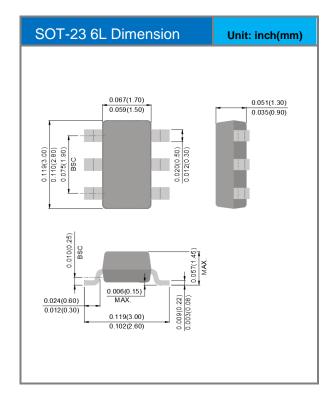
Fig.9 Capacitance vs. Drain-Source Voltage

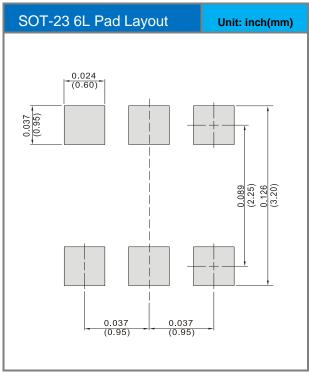


Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJS6403-AU	SOT-23 6L	3K pcs / 7" reel	S03	

Packaging Information & Mounting Pad Layout







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